

WHAT IS CLAIMED IS:

1. A method for designing a semiconductor having a computer for inserting a dummy pattern between design patterns, the method comprising the steps of:

5 dividing a layout pattern for a layout layer in a semiconductor device into divided areas;

 inserting a dummy pattern between design patterns in the divided areas;

 calculating the density of the dummy pattern and
10 the design patterns in each of the divided areas; and

 changing pattern rules for the dummy pattern so that the density will be desired values.

2. The method for designing a semiconductor device
15 according to claim 1, wherein the design patterns are wiring patterns and the layout layer is a wiring layer.

3. The method for designing a semiconductor device according to claim 1, wherein:

20 division specification information regarding size of the divided areas is accepted; and

 the layout pattern is divided into divided areas having the size of which is specified by the division specification information.

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4. The method for designing a semiconductor device according to claim 1, wherein:

generated dummy specification information regarding the specification of the divided area in which the dummy pattern is to be inserted is accepted; and

the dummy pattern is inserted between design
5 patterns in the divided area specified by the generated dummy specification information.

5. The method for designing a semiconductor device according to claim 1, wherein:

10 dummy rule information regarding pattern rules for the dummy pattern inserted between the design patterns is accepted; and

the dummy pattern having the pattern rules for which are based on the dummy rule information is inserted
15 between the design patterns.

6. The method for designing a semiconductor device according to claim 1, wherein the dummy pattern is inserted between design patterns in an area including the
20 divided area and a divided area adjacent to the divided area.

7. The method for designing a semiconductor device according to claim 1, wherein if the density does not
25 match the desired values, the density of the dummy pattern and the design patterns in an area obtained by enlarging the divided area where the density was calculated is

calculated.

8. The method for designing a semiconductor device according to claim 1, wherein if the density does not
5 match the desired values, the density of the dummy pattern and the design patterns in an area including the divided area where the density was calculated and a divided area adjacent to the divided area is calculated.

10 9. The method for designing a semiconductor device according to claim 1, wherein the density of design patterns and dummy patterns on the entire layout pattern is calculated.

15 10. A program for designing a semiconductor device which inserts a dummy pattern between design patterns, the program making a computer perform the processes of:

dividing a layout pattern for a layout layer in a semiconductor device into divided areas;

20 inserting a dummy pattern between design patterns in the divided areas;

calculating the density of the dummy pattern and the design patterns in each of the divided areas; and

changing pattern rules for the dummy pattern so
25 that the density will be desired values.

11. A computer-readable record medium which stores

a program for designing a semiconductor device which inserts a dummy pattern between design patterns, the program making a computer perform the processes of:

dividing a layout pattern for a layout layer in a
5 semiconductor device into divided areas;

inserting a dummy pattern between design patterns in the divided areas;

calculating the density of the dummy pattern and the design patterns in each of the divided areas; and

10 changing pattern rules for the dummy pattern so that the density will be desired values.

12. An apparatus for designing a semiconductor device which inserts a dummy pattern between design
15 patterns, the apparatus comprising:

a dividing section for dividing a layout pattern for a layout layer in a semiconductor device into divided areas;

an inserting section for inserting a dummy pattern
20 between design patterns in the divided areas;

a calculating section for calculating the density of the dummy pattern and the design patterns in each of the divided areas; and

a changing section for changing pattern rules for
25 the dummy pattern so that the density will be desired values.